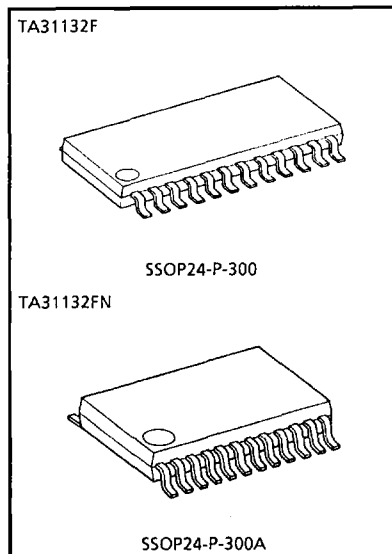


# IF DETECT ICs

## FM IF DETECTION IC FOR CORDLESS TELEPHONE·MOBILE TELEPHONE

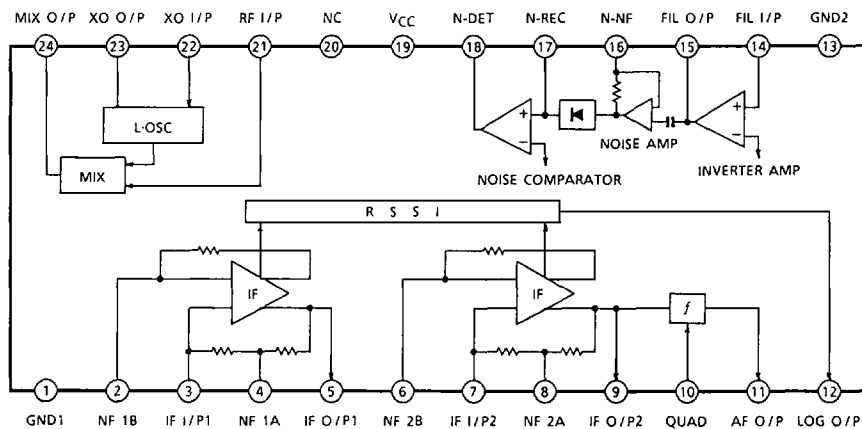
### FEATURES

- Built-in 2nd MIX  
MIX Operating Frequency : 10~100MHz
- 2 IF amp. circuits can limit a Band width according to a usage
- IF amp. has high performance carrier detection (RSSI)  
: it is available to diversity application
- Built-in 4 circuits (INVERTER AMP, NOISE AMP, noise rectifier and comparator) for noise detection
- Low consumption current (Typ. : 3.4mA)
- Operating supply voltage range : 2.7~6.0V



Weight SSOP24-P-300 : 1.2g (Typ.)  
SSOP24-P-300A : 0.14g (Typ.)

### BLOCK DIAGRAM



TA31132F/FN-1



# IF DETECT ICs

PIN FUNCTION (The values of resistor and capacitor are typical.)

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
1	GND1	GND for IF1, MIX etc.	—
2	NF 1B	Negative feedback (NF) pin to IF1 amp. Connect GND through a capacitor.	
3	IF I/P1	Input pin for IF1 amp. Connect a capacitor for coupling.	
4	NF 1A	Connect a coupling capacitor for feedback loop of IF1 amp.	
5	IF O/P1	Output for IF1 amp. In case of connecting a ceramic filter, connect a resistance for matching.	
6	NF 2B	Negative feedback (NF) pin to IF2 amp. Connect GND through a capacitor.	
7	IF I/P2	Input pin for IF2 amp. Connect a capacitor for coupling.	
8	NF 2A	Connect a coupling capacitor for feedback loop of IF2 amp.	
9	IF O/P2	Output pin for IF2 amp. Connect to a detection coil through a capacitor.	
10	QUAD	Input pin for FM demodulator. Connect to a detection coil through a capacitor.	
11	AF O/P	Output pin for FM demodulator. Output impedance is around 1kΩ. Connect a De Emp, BPF circuit for excepting IF frequency element on this pin.	
12	LOG O/P	RSSI output pin. Output impedance is around 56kΩ. Connect the capacitor 1000pF for smoothing.	

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# IF DETECT ICs

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
13	GND2	GND for IF2 amp., noise detector etc.	—
14	FIL I/P	Input pin for BPF Adjustable frequency with a capacitor and resistance. Application circuit has around 26kHz.	
15	FIL O/P	Output pin for BPF	
16	N-NF	NF pin for NOISE AMP	
17	N-REC	Rectifier output pin. Connect a capacitor for smoothing.	
18	N-DET	NOISE COMPARATOR output pin.	
19	VCC	Power supply terminal.	—
20	NC	NC terminal.	—
21	RF I/P	Input pin for MIX. Input impedance is around 7kΩ. Double-balance mix. method is used.	



# IF DETECT ICs

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
22	XO I/P	L-OSC input pin. Available to connect X'tal oscillator.	
23	XO O/P	L-OSC output pin. In case of injecting L-OSC, inject from pin 22 or 23 through a capacitor.	
24	MIX O/P	MIX output pin. For open collector output circuit, connect to V <sub>CC</sub> through load.	

## 1. MIX

This IC uses the MIX of double-balanced type.

Connect a proper external circuit to match the Input impedance around  $7k\Omega$ .

The application circuit has a matched LC resonance circuit, and the gain of around 10dB.

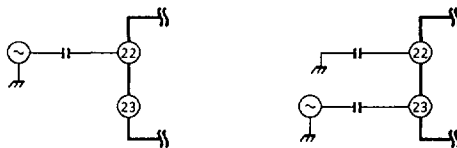
Connect matching resistance for ceramic filter between output pin (pin 24) and V<sub>CC</sub> because of open collector output (pin 24).

## 2. L-OSC

Osc. level of X'tal osc. circuit is  $110dB\mu V$  ( $316mV_{rms}$ , typ.).

In case of directly inputting.

Local osc signal, connect as follows.



## 3. IF limiter and ceramic filter

This IC has double constitution of IF limiter amp.

It is available to be larger separation between 2 channels by changing band width of sub-filter.

Connect a filter to serve an application.

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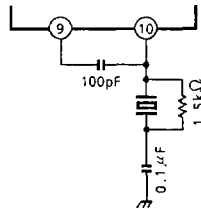
## 4. Detector

This IC uses a quadrature FM detection circuit.

Input to pin 10 the signal to shift the phase of IF amp. Output in 90 degree with RCL resonance circuit. Tune with tank circuit.

(Recommended tank circuit : 4164-102 (SUMIDA ELECTRONICS CO., LTD.) )

In case of connecting the discriminator, connect as follows.



Ceramic discriminator  
CDBM450C21

## 5. Demodulator output

The demodulated signal is output from pin 11.

Connect de-emphasis circuit and BPF for excepting carrier element in the demodulator output (pin 11). On the TA31132F test circuit, connect the de-emphasis (0dB (at 1kHz), -6dB/OCT.) and BPF (300Hz~3kHz).

## 6. RSSI circuit

Available to detect the input signal level with DC voltage on RSSI circuit.

IF input level keeps the linear characteristic period between 20dB $\mu$ V and 100dB $\mu$ V.

The temperature regulation is very small.

The RSSI output is DC voltage on pin 12.

To change the output voltage is to connect a resistance between pin 12 and GND (in parallel with internal resistance 56k $\Omega$ ). But this IC has no temperature regulation internally, so note temperature regulation of external resistance. (In case of changing RSSI output voltage, connect the resistance to have small temperature regulation.)

## 7. Noise detection circuit

Noise detection circuit has INVERTER AMP for filter, NOISE AMP and Noise rectifier circuit and comparator.

The BPF is constituted by INVERTER AMP In case of changing input frequency, change the value for resistance and capacitor of pin 14, 15. (on the test circuit,  $f_0 = 26\text{kHz}$ )

The gain of Noise AMP is around 67dB. Connect the smoothing capacitor (0.1 $\mu$ F) for rectified output on pin 17.

The reference of NOISE COMPARATOR is 0.85V (typ.)

When Noise level is large, the comparator output (pin 18) change from H to L level.

When BPF does not get the frequency to be needed, NOISE COMPARATOR output may be unstable.

Give attention to connection in Noise detection circuit.

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# IF DETECT ICs

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	6.5	V
Power Dissipation	31132FN	350	mW
	31132F	450	
Operating Temperature	T <sub>opr</sub>	-30~85	°C
Storage Temperature	T <sub>stg</sub>	-50~150	°C

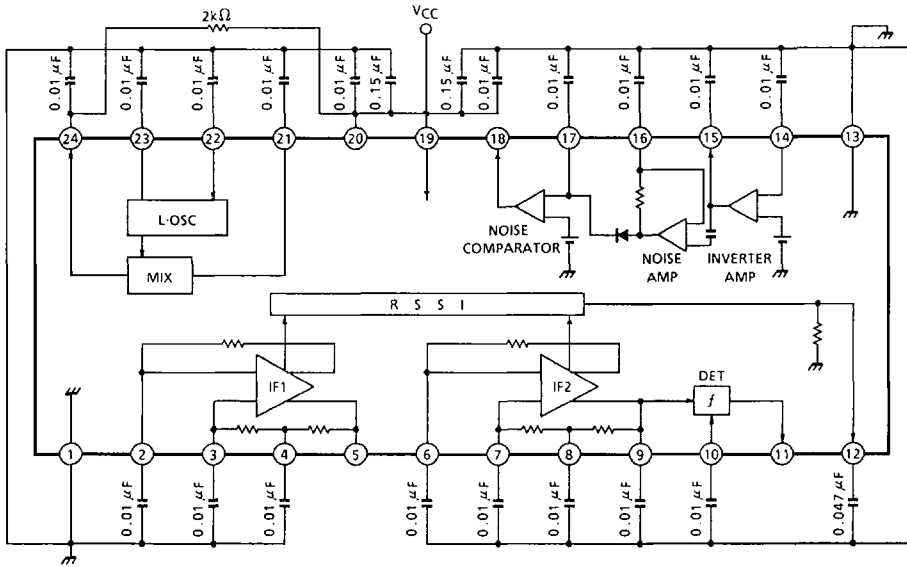
ELECTRICAL CHARACTERISTICS (Unless otherwise specified, Ta = 25°C, V<sub>CC</sub> = 3.5V, f<sub>I</sub> (MIX) = 21.7MHz, Δf = ±1.75kHz, f<sub>MOD</sub> = 1kHz, f<sub>I</sub> (IF) = 450kHz)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Quiescent Current	I <sub>CCQ</sub>	1	—	2.4	3.4	5.0	mA
MIX Conversion Gain	G <sub>VC</sub>	2	V <sub>I</sub> (MIX) = 20dBμV	15	20	26	dB
Local Oscillation Voltage	V <sub>LO</sub>	—	—	—	110	—	dBμV
Pre-stage IF Amp. Gain	G <sub>IF1</sub>	—	—	—	66	—	dB
Following-stage IF Amp. Gain	G <sub>IF2</sub>	—	—	—	52	—	dB
Level Detection Output 1	V <sub>RSSI-1</sub>	2	V <sub>I</sub> (IF) = 20dBμV	0.3	0.42	0.6	V
Level Detection Output 2	V <sub>RSSI-2</sub>	2	V <sub>I</sub> (IF) = 100dBμV	1.8	2.1	2.5	V
Demodulation Output	V <sub>OD</sub>	2	V <sub>I</sub> (IF) = 60dBμV, with De Emp and BPF	32	45	56	mV <sub>rms</sub>
Noise Rectifier Output 1	V <sub>NREC-1</sub>	2	f <sub>N</sub> = 26kHz, V <sub>I</sub> (N) = 1mV <sub>rms</sub>	—	0.1	0.6	V
Noise Rectifier Output 2	V <sub>NREC-2</sub>	2	f <sub>N</sub> = 26kHz, V <sub>I</sub> (N) = 10mV <sub>rms</sub>	1.7	2.2	2.5	V
Noise Detection Output 1	V <sub>NDET-1</sub>	2	f <sub>N</sub> = 26kHz, V <sub>I</sub> (N) = 1mV <sub>rms</sub>	—	—	100	mV
Noise Detection Output 2	V <sub>NDET-2</sub>	2	f <sub>N</sub> = 26kHz, V <sub>I</sub> (N) = 10mV <sub>rms</sub>	3.2	—	—	V
Signal To Noise Ratio	S/N-1	2	V <sub>I</sub> (IF) = 20dBμV	22	25	—	dB
Signal To Noise Ratio	S/N-2	2	V <sub>I</sub> (IF) = 70dBμV	50	55	—	dB
AM Rejection Ratio	AMR	—	V <sub>I</sub> (IF) = 70dBμV, AM = 30%	—	45	—	dB
MIX Input Impedance	R <sub>IN</sub> (MIX)	—	—	—	7	—	kΩ

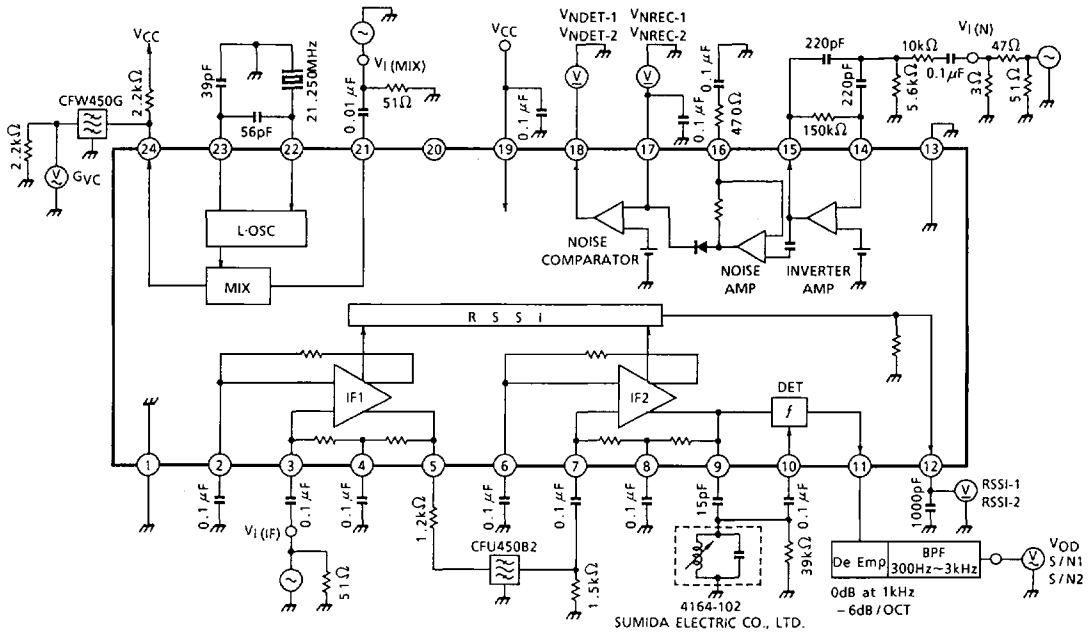
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# IF DETECT ICs

TEST CIRCUIT (1)

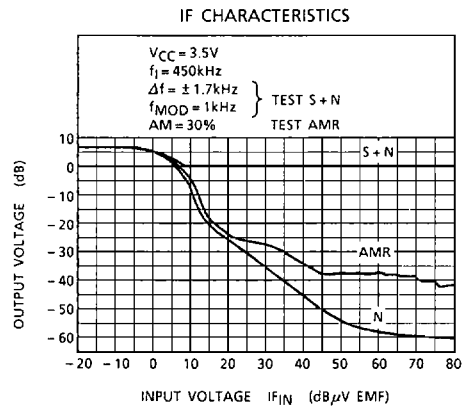
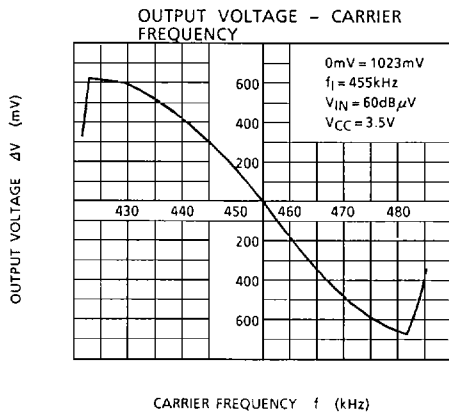
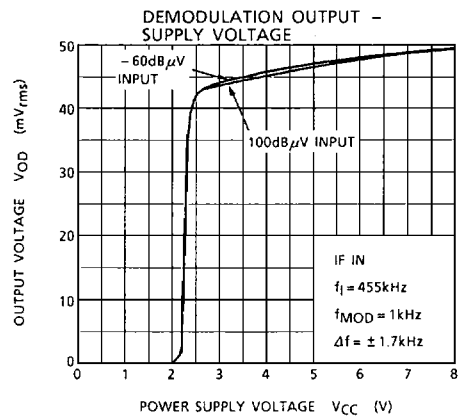
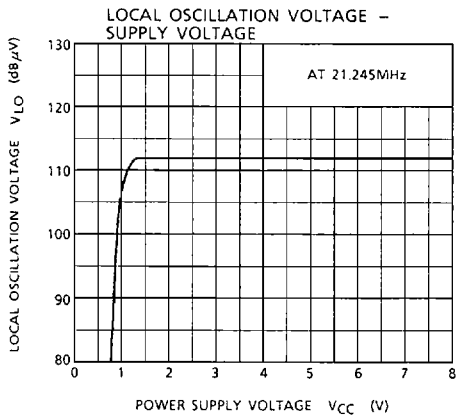
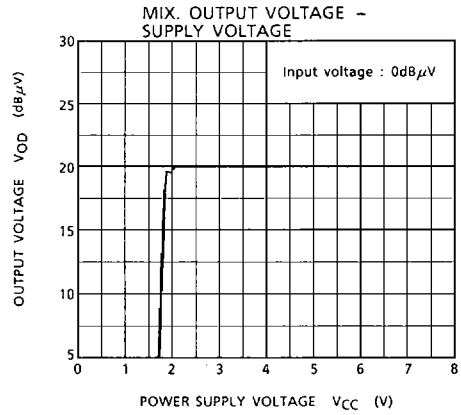
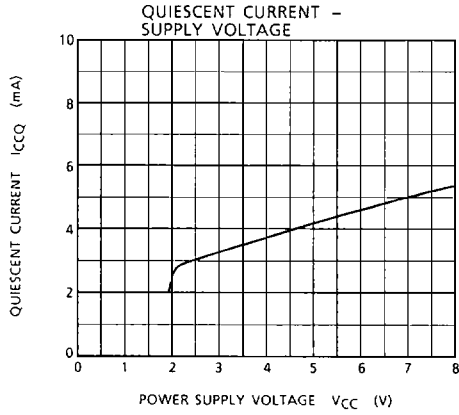


TEST CIRCUIT (2)



TA31132F/FN-7

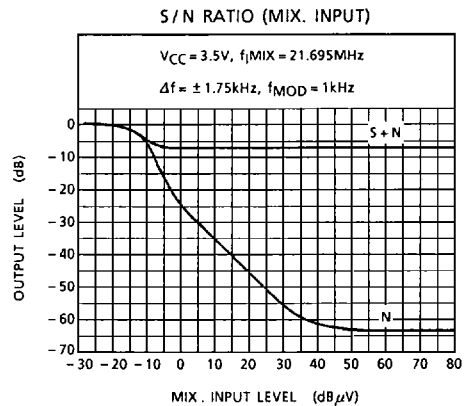
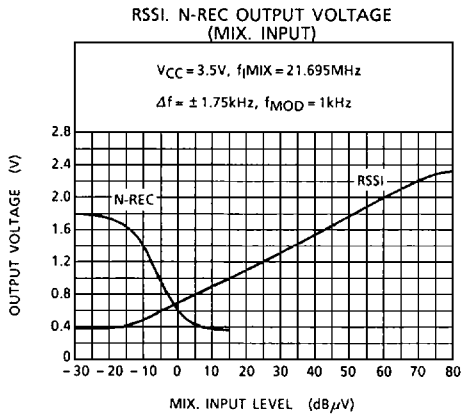
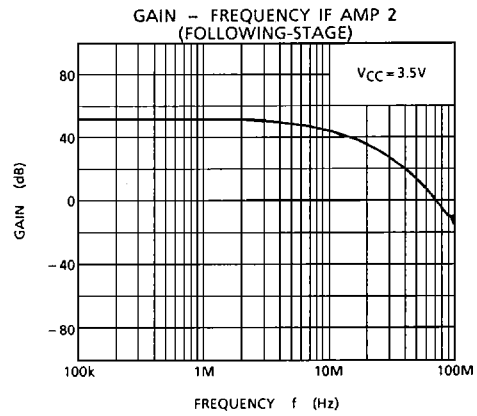
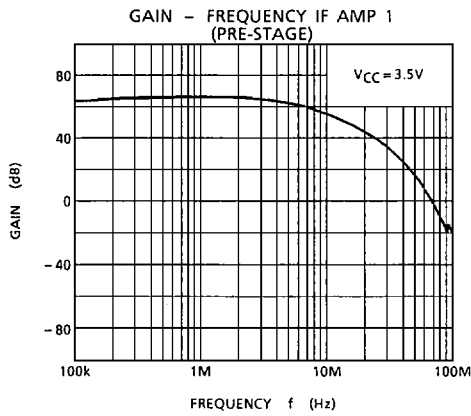
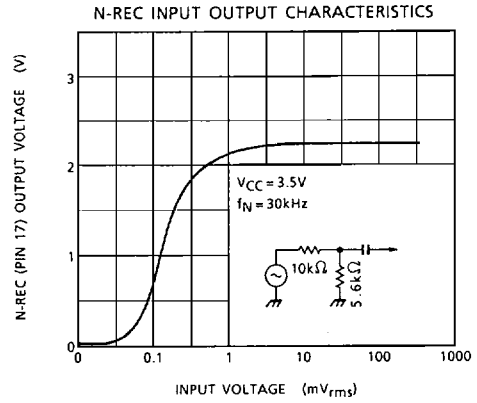
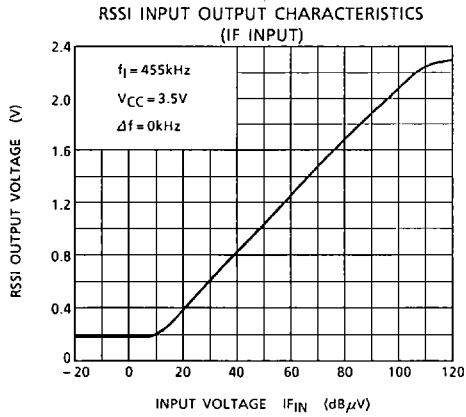
# IF DETECT ICs



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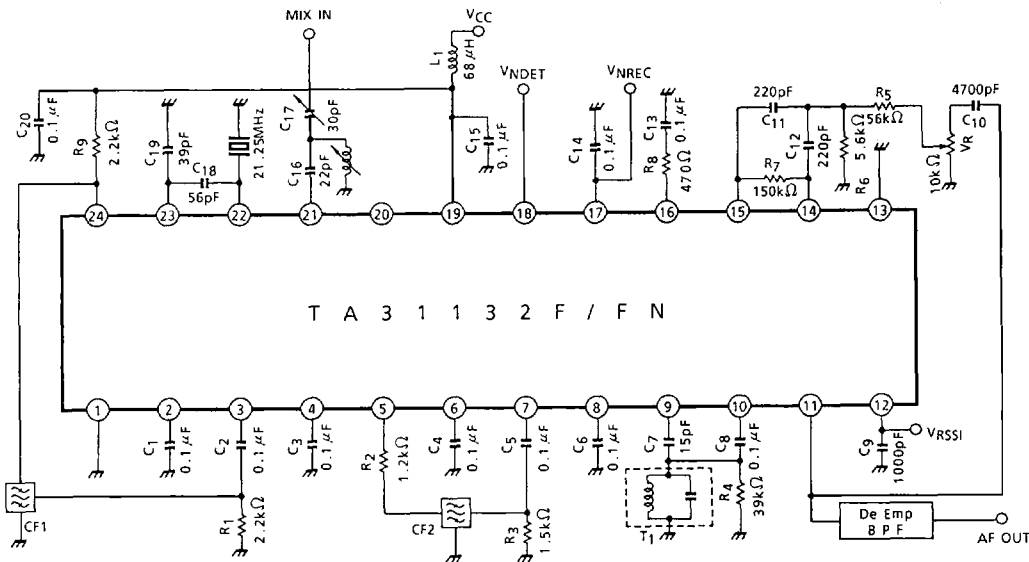


# IF DETECT ICs



# IF DETECT ICs

## REFERENCE CIRCUIT



- CF1 : CFW450G (MURATA MFG. CO.,LTD)
- CF2 : CFU450B2 (MURATA MFG. CO.,LTD)
- T1 : 4164-102 (SUMIDA ELECTRIC CO.,LTD)

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